



120V NPN DARLINGTON TRANSISTOR IN SOT223

Features

- BV_{CEO} > 120V
- BV_{CBO} > 140V
- I_C = 1.5A High Continuous current
- hFE > 2k for High Gain @ 1A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

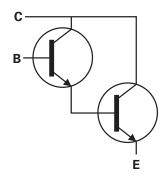
- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (a)
- Weight: 0.112 grams (approximate)

Applications

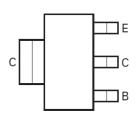
- Lamp
- Relay
- Solenoid Driving







Device Symbol



Top View Pin-Out

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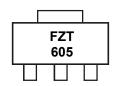
Ordering Information (Note 4)

| Product | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|----------|---------|--------------------|-----------------|-------------------|
| FZT605TA | FZT605 | 7 | 12 | 1,000 |
| FZT605TC | FZT605 | 13 | 12 | 4,000 |

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information



FZT605= Product Type Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|-----------------|-------|------|
| Collector-Base Voltage | V_{CBO} | 140 | V |
| Collector-Emitter Voltage | V_{CEO} | 120 | V |
| Emitter-Base Voltage | V_{EBO} | 14 | V |
| Continuous Collector Current | lc | 1.5 | Α |
| Peak Pulse Current | I _{CM} | 4 | Α |

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|--|-------------------|------------------|-------|------|
| Power Dissipation | (Note 5) | 0 | 2 | W |
| Power Dissipation | (Note 6) | P _D | 3 | W |
| Thermal Desistance Junction to Ambient | (Note 5) | - | 62.5 | °C/W |
| Thermal Resistance, Junction to Ambient | (Note 6) | $R_{\theta JA}$ | 41.7 | °C/W |
| Thermal Resistance, Junction to Leads (Note 7) | | R _{0JL} | 12.93 | °C/W |
| Operating and Storage Temperature Range | $T_{J_i} T_{STG}$ | -55 to +150 | °C | |

ESD Ratings (Note 8)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | ≥ 400 | V | С |

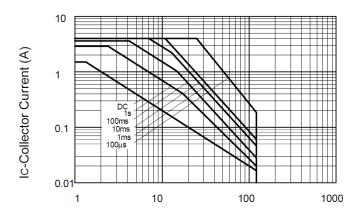
Notes:

- 5. For a device mounted on 25mm X 25mm 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (5), except the device is mounted on 50mm X 50mm 2oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).

 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

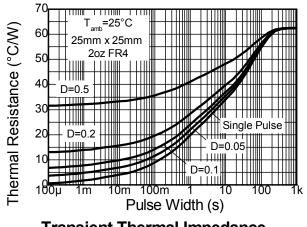


Thermal Characteristics and Derating Information

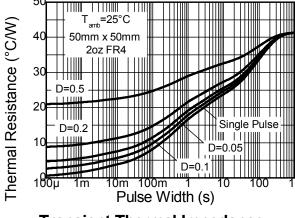


VCE - Collector Emitter Voltage (V)

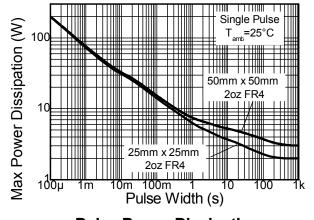
FZT605 Safe Operating Area



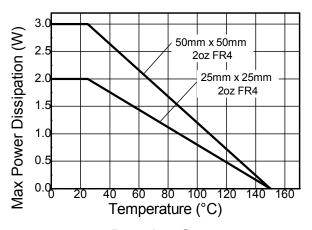
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation



Derating Curve



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

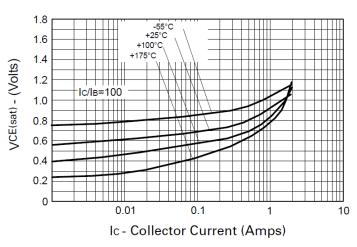
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|---|----------------------|--------------------------------|-------------|------------------------|----------|---|
| Collector-Base Breakdown Voltage | BV _{CBO} | 140 | _ | _ | V | I _C = 100μA |
| Collector-Emitter Breakdown Voltage (Note 9) | BV _{CEO} | 120 | _ | _ | V | I _C = 1mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | 14 | _ | _ | V | I _E = 100μA |
| Collector-Base Cutoff Current | I _{CBO} | - | _ | 100 10 | nΑ μΑ | V _{CB} = 120V V _{CB} = 120V, T _A = +120°C |
| Collector-Emitter Cutoff Current | I _{CES} | - | _ | 100 | nA | V _{CE} = 120V |
| Emitter Cutoff Current | I _{EBO} | - | _ | 100 | nA | V _{EB} = 8V |
| DC Current Gain (Note 9) | h _{FE} | 2,000 5,000 2,000 500 | - - - | _ _ 100,000 _ | - | I_{C} = 50mA, V_{CE} = 5V I_{C} = 500mA, V_{CE} = 5V I_{C} = 1A, V_{CE} = 5V I_{C} = 2A, V_{CE} = 5V |
| Collector-Emitter Saturation Voltage (Note 9) | V _{CE(sat)} | _ | _ | 1 1.5 | V | I _C = 250mA, I _B = 0.25mA I _C = 1A, I _B = 1mA |
| Base-Emitter Saturation Voltage (Note 9) | V _{BE(sat)} | _ | _ | 1.8 | V | I _C = 1A, I _B = 1mA |
| Base-Emitter Turn-On Voltage (Note 9) | V _{BE(on)} | _ | _ | 1.7 | V | I _C = 1A, V _{CE} = 5V |
| Input Capacitance (Note 9) | C _{ibo} | _ | 90 | _ | pF | V _{EB} = 0.5V, f = 1MHz |
| Output Capacitance (Note 9) | C _{obo} | _ | 15 | _ | pF | V _{CB} = 10V, f = 1MHz |
| Current Gain-Bandwidth Product (Note 9) | f _T | 150 | _ | _ | MHz | V _{CE} = 10V, I _C = 100mA, f=20MHz |
| Turn-On Time | t _{on} | _ | 0.5 | _ | μs | V _{CC} = 10V, I _C = 500mA |
| Turn-Off Time | t _{off} | | 1.6 | | μs | $I_{B1} = -I_{B2} = 0.5 \text{mA}$ |

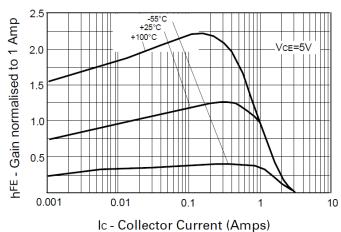
Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.





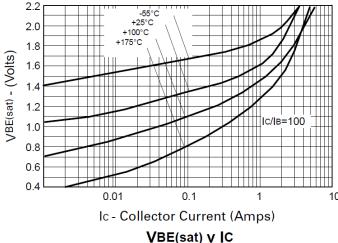
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

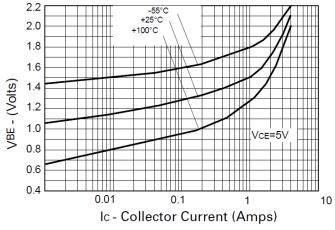




VCE(sat) v IC





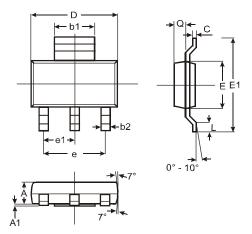


VBE(on) v IC



Package Outline Dimensions

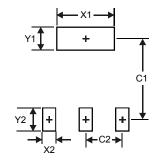
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| SOT223 | | | | | |
|----------------------|-------|------|------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 1.55 | 1.65 | 1.60 | | |
| A1 | 0.010 | 0.15 | 0.05 | | |
| b1 | 2.90 | 3.10 | 3.00 | | |
| b2 | 0.60 | 0.80 | 0.70 | | |
| С | 0.20 | 0.30 | 0.25 | | |
| D | 6.45 | 6.55 | 6.50 | | |
| Е | 3.45 | 3.55 | 3.50 | | |
| E1 | 6.90 | 7.10 | 7.00 | | |
| е | | _ | 4.60 | | |
| e1 | | _ | 2.30 | | |
| L | 0.85 | 1.05 | 0.95 | | |
| q | 0.84 | 0.94 | 0.89 | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| X1 | 3.3 |
| X2 | 1.2 |
| Y1 | 1.6 |
| Y2 | 1.6 |
| C1 | 6.4 |
| C2 | 2.3 |

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.





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